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Applications of "<u>Embedded - Microcontrollers</u>"

Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c55-lpi-p
Supplier Device Package	28-PDIP
Package / Case	28-DIP (0.600", 15.24mm)
Mounting Type	Through Hole
Operating Temperature	-40°C ~ 85°C (TA)
Oscillator Type	External
Data Converters	-
Voltage - Supply (Vcc/Vdd)	2.5V ~ 6.25V
RAM Size	24 x 8
EEPROM Size	-
Program Memory Type	ОТР
Program Memory Size	768B (512 x 12)
Number of I/O	20
Peripherals	POR, WDT
Connectivity	-
Speed	40MHz
Core Size	8-Bit
Core Processor	PIC
Product Status	Active
Details	

# PIC16C5X

TABLE 1-1: PIC16C5X FAMILY OF DEVICES

Features	PIC16C54	PIC16CR54	PIC16C55	PIC16C56	PIC16CR56
Maximum Operation Frequency	40 MHz	20 MHz	40 MHz	40 MHz	20 MHz
EPROM Program Memory (x12 words)	512	_	512	1K	_
ROM Program Memory (x12 words)	_	512	_	_	1K
RAM Data Memory (bytes)	25	25	24	25	25
Timer Module(s)	TMR0	TMR0	TMR0	TMR0	TMR0
I/O Pins	12	12	20	12	12
Number of Instructions	33	33	33	33	33
Packages	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	28-pin DIP, SOIC; 28-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP

All PIC® Family devices have Power-on Reset, selectable Watchdog Timer, selectable Code Protect and high I/O current capability.

Features	PIC16C57	PIC16CR57	PIC16C58	PIC16CR58
Maximum Operation Frequency	40 MHz	20 MHz	40 MHz	20 MHz
EPROM Program Memory (x12 words)	2K	_	2K	_
ROM Program Memory (x12 words)	_	2K	_	2K
RAM Data Memory (bytes)	72	72	73	73
Timer Module(s)	TMR0	TMR0	TMR0	TMR0
I/O Pins	20	20	12	12
Number of Instructions	33	33	33	33
Packages	28-pin DIP, SOIC; 28-pin SSOP	28-pin DIP, SOIC; 28-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP

All  $PIC^{\otimes}$  Family devices have Power-on Reset, selectable Watchdog Timer, selectable Code Protect and high I/O current capability.

TABLE 3-1: PINOUT DESCRIPTION - PIC16C54, PIC16C54, PIC16C56, PIC16C756, PIC16C758, PIC16C758

D' N	Pi	n Numb	er	Pin	Buffer	B t di
Pin Name	DIP	SOIC	SSOP	Туре	Туре	Description
RA0	17	17	19	I/O	TTL	Bi-directional I/O port
RA1	18	18	20	I/O	TTL	
RA2	1	1	1	I/O	TTL	
RA3	2	2	2	I/O	TTL	
RB0	6	6	7	I/O	TTL	Bi-directional I/O port
RB1	7	7	8	I/O	TTL	
RB2	8	8	9	I/O	TTL	
RB3	9	9	10	I/O	TTL	
RB4	10	10	11	I/O	TTL	
RB5	11	11	12	I/O	TTL	
RB6	12	12	13	I/O	TTL	
RB7	13	13	14	I/O	TTL	
T0CKI	3	3	3	I	ST	Clock input to Timer0. Must be tied to Vss or VDD, if not in
						use, to reduce current consumption.
MCLR/VPP	4	4	4	I	ST	Master clear (RESET) input/programming voltage input.
						This pin is an active low RESET to the device. Voltage on the MCLR/VPP pin must not exceed VDD to avoid unin-
						tended entering of Programming mode.
OSC1/CLKIN	16	16	18	I	ST	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	15	15	17	0		Oscillator crystal output. Connects to crystal or resonator
						in crystal Oscillator mode. In RC mode, OSC2 pin outputs
						CLKOUT, which has 1/4 the frequency of OSC1 and
						denotes the instruction cycle rate.
VDD	14	14	15,16	Р	_	Positive supply for logic and I/O pins.
Vss	5	5	5,6	Р	_	Ground reference for logic and I/O pins.

Legend: I = input, O = output, I/O = input/output, P = power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input

# 3.1 Clocking Scheme/Instruction Cycle

The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks, namely Q1, Q2, Q3 and Q4. Internally, the program counter is incremented every Q1 and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow are shown in Figure 3-2 and Example 3-1.

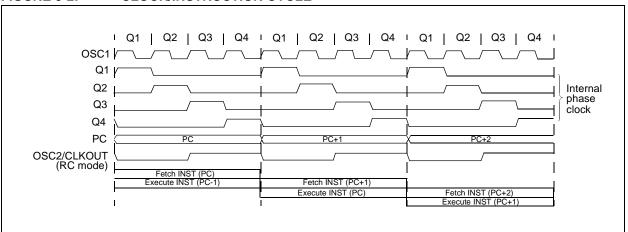
#### 3.2 Instruction Flow/Pipelining

An Instruction Cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute takes another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the program counter to change (e.g., GOTO), then two cycles are required to complete the instruction (Example 3-1).

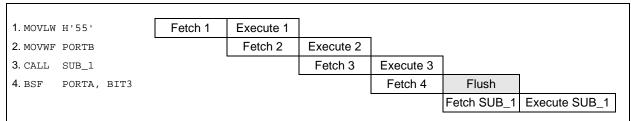
A fetch cycle begins with the program counter (PC) incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).

FIGURE 3-2: CLOCK/INSTRUCTION CYCLE



#### **EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW**



All instructions are single cycle, except for any program branches. These take two cycles since the fetch instruction is "flushed" from the pipeline, while the new instruction is being fetched and then executed.

#### 5.0 RESET

PIC16C5X devices may be RESET in one of the following ways:

- Power-On Reset (POR)
- MCLR Reset (normal operation)
- MCLR Wake-up Reset (from SLEEP)
- WDT Reset (normal operation)
- WDT Wake-up Reset (from SLEEP)

Table 5-1 shows these RESET conditions for the PCL and STATUS registers.

Some registers are not affected in any RESET condition. Their status is unknown on POR and unchanged in any other RESET. Most other registers are reset to a "RESET state" on Power-On Reset (POR), MCLR or WDT Reset. A MCLR or WDT wake-up from SLEEP also results in a device RESET, and not a continuation of operation before SLEEP.

The TO and PD bits (STATUS <4:3>) are set or cleared depending on the different RESET conditions (Table 5-1). These bits may be used to determine the nature of the RESET.

Table 5-3 lists a full description of RESET states of all registers. Figure 5-1 shows a simplified block diagram of the On-chip Reset circuit.

TABLE 5-1: STATUS BITS AND THEIR SIGNIFICANCE

Condition	TO	PD
Power-On Reset	1	1
MCLR Reset (normal operation)	u	u
MCLR Wake-up (from SLEEP)	1	0
WDT Reset (normal operation)	0	1
WDT Wake-up (from SLEEP)	0	0

Legend: u = unchanged, x = unknown, -= unimplemented read as '0'.

TABLE 5-2: SUMMARY OF REGISTERS ASSOCIATED WITH RESET

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR	Value on MCLR and WDT Reset
03h	STATUS	PA2	PA1	PA0	TO	PD	Z	DC	С	0001 1xxx	000q quuu

Legend: u = unchanged, x = unknown, q = see Table 5-1 for possible values.

FIGURE 5-3: TIME-OUT SEQUENCE ON POWER-UP (MCLR NOT TIED TO VDD)

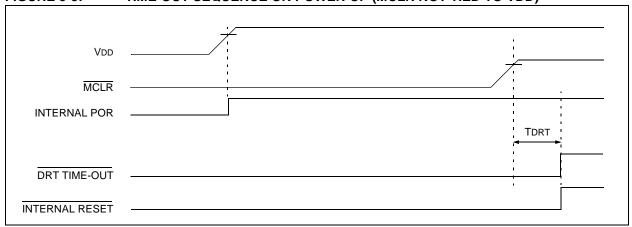


FIGURE 5-4: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): FAST VDD RISE TIME

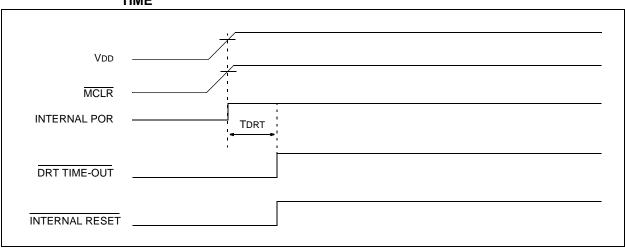
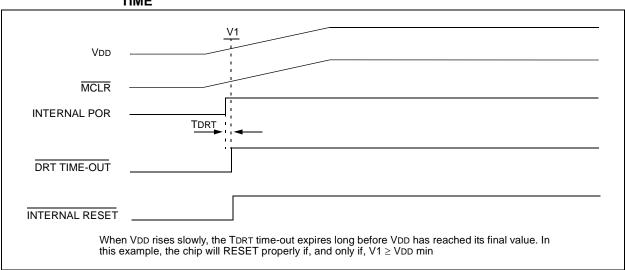


FIGURE 5-5: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): SLOW VDD RISE TIME



#### 6.5 Program Counter

As a program instruction is executed, the Program Counter (PC) will contain the address of the next program instruction to be executed. The PC value is increased by one, every instruction cycle, unless an instruction changes the PC.

For a GOTO instruction, bits 8:0 of the PC are provided by the GOTO instruction word. The PC Latch (PCL) is mapped to PC<7:0> (Figure 6-7, Figure 6-8 and Figure 6-9).

For the PIC16C56, PIC16CR56, PIC16C57, PIC16CR57, PIC16C58 and PIC16CR58, a page number must be supplied as well. Bit5 and bit6 of the STATUS Register provide page information to bit9 and bit10 of the PC (Figure 6-8 and Figure 6-9).

For a CALL instruction, or any instruction where the PCL is the destination, bits 7:0 of the PC again are provided by the instruction word. However, PC<8> does not come from the instruction word, but is always cleared (Figure 6-7 and Figure 6-8).

Instructions where the PCL is the destination, or modify PCL instructions, include MOVWF PCL, ADDWF PCL, and BSF PCL, 5.

For the PIC16C56, PIC16CR56, PIC16C57, PIC16CR57, PIC16C58 and PIC16CR58, a page number again must be supplied. Bit5 and bit6 of the STATUS Register provide page information to bit9 and bit10 of the PC (Figure 6-8 and Figure 6-9).

**Note:** Because PC<8> is cleared in the CALL instruction, or any modify PCL instruction, all subroutine calls or computed jumps are limited to the first 256 locations of any program memory page (512 words long).

FIGURE 6-7: LOADING OF PC
BRANCH INSTRUCTIONS
- PIC16C54, PIC16CR54,

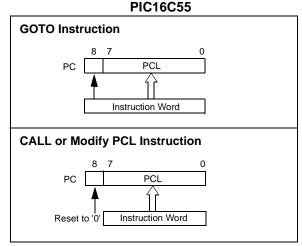


FIGURE 6-8: LOADING OF PC
BRANCH INSTRUCTIONS

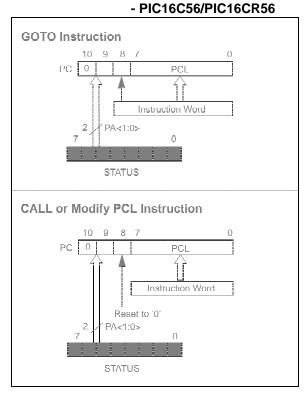
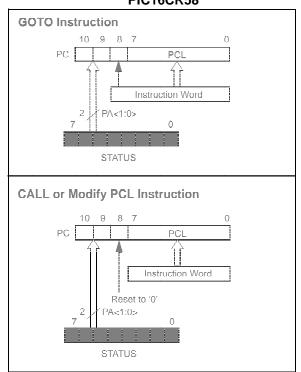


FIGURE 6-9: LOADING OF PC
BRANCH INSTRUCTIONS
- PIC16C57/PIC16CR57,
AND PIC16C58/
PIC16CR58



# 6.5.1 PAGING CONSIDERATIONS – PIC16C56/CR56, PIC16C57/CR57 AND PIC16C58/CR58

If the Program Counter is pointing to the last address of a selected memory page, when it increments it will cause the program to continue in the next higher page. However, the page preselect bits in the STATUS Register will not be updated. Therefore, the next GOTO, CALL or modify PCL instruction will send the program to the page specified by the page preselect bits (PAO or PA<1:0>).

For example, a NOP at location 1FFh (page 0) increments the PC to 200h (page 1). A GOTO xxx at 200h will return the program to address xxh on page 0 (assuming that PA<1:0> are clear).

To prevent this, the page preselect bits must be updated under program control.

#### 6.5.2 EFFECTS OF RESET

The Program Counter is set upon a RESET, which means that the PC addresses the last location in the last page (i.e., the RESET vector).

The STATUS Register page preselect bits are cleared upon a RESET, which means that page 0 is preselected.

Therefore, upon a RESET, a GOTO instruction at the RESET vector location will automatically cause the program to jump to page 0.

#### 6.6 Stack

PIC16C5X devices have a 10-bit or 11-bit wide, two-level hardware push/pop stack.

A CALL instruction will push the current value of stack 1 into stack 2 and then push the current program counter value, incremented by one, into stack level 1. If more than two sequential CALL's are executed, only the most recent two return addresses are stored.

A RETLW instruction will pop the contents of stack level 1 into the program counter and then copy stack level 2 contents into level 1. If more than two sequential RETLW's are executed, the stack will be filled with the address previously stored in level 2. Note that the W Register will be loaded with the literal value specified in the instruction. This is particularly useful for the implementation of data look-up tables within the program memory.

For the RETLW instruction, the PC is loaded with the Top of Stack (TOS) contents. All of the devices covered in this data sheet have a two-level stack. The stack has the same bit width as the device PC, therefore, paging is not an issue when returning from a subroutine.

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#### 12.1 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)

PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)			Standard Operating Conditions (unless otherwise specified Operating Temperature 0°C ≤ TA ≤ +70°C for commercial																
Param No.	Symbol	Characteristic/Device		I Characteristic/Device		I Characteristic/Device		Characteristic/Device		Characteristic/Device		Characteristic/Device		Characteristic/Device		Тур†	Max	Units	Conditions
D001	VDD	Supply Voltage PIC16C5X-RC PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-LP	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V													
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>		1.5*	_	V	Device in SLEEP Mode												
D003	VPOR	VDD Start Voltage to ensure Power-on Reset		Vss	_	V	See Section 5.1 for details on Power-on Reset												
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset												
D010	IDD	Supply Current <sup>(2)</sup> PIC16C5X-RC <sup>(3)</sup> PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-HS PIC16C5X-LP		1.8 1.8 4.8 4.8 9.0	3.3 3.3 10 10 20 32	mA mA mA mA mA	FOSC = 4 MHz, VDD = 5.5V FOSC = 4 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 20 MHz, VDD = 5.5V FOSC = 32 kHz, VDD = 3.0V, WDT disabled												
D020	IPD	Power-down Current <sup>(2)</sup>	_	4.0 0.6	12 9	μA μA	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled												

<sup>\*</sup> These parameters are characterized but not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD,  $\overline{MCLR} = VDD$ ; WDT enabled/disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in  $k\Omega$ .

<sup>†</sup> Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

# 12.4 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial) PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

DC CH	ARACTE	RISTICS	Standard Operating Conditions (unless otherwise specified)  Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial						
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions		
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	Vss Vss Vss Vss Vss	_ _ _ _	0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V	Pin at hi-impedance PIC16C5X-RC only <sup>(3)</sup> PIC16C5X-XT, 10, HS, LP		
D040	VIH	Input High Voltage I/O ports I/O ports I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	0.45 VDD 2.0 0.36 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD	V V V V V	For all VDD <sup>(4)</sup> 4.0V < VDD ≤ 5.5V <sup>(4)</sup> VDD > 5.5V  PIC16C5X-RC only <sup>(3)</sup> PIC16C5X-XT, 10, HS, LP		
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	_	_	V			
D060	IIL	Input Leakage Current <sup>(1,2)</sup> I/O ports  MCLR MCLR TOCKI OSC1	-1 -5 -3 -3	0.5 — 0.5 0.5 0.5	+1  +5 +3 +3	μΑ μΑ μΑ μΑ μΑ	For Vdd $\leq$ 5.5V: VSS $\leq$ VPIN $\leq$ VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD VSS $\leq$ VPIN $\leq$ VDD VSS $\leq$ VPIN $\leq$ VDD, PIC16C5X-XT, 10, HS, LP		
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT	_	_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, PIC16C5X-RC		
D090	Voн	Output High Voltage <sup>(2)</sup> I/O ports OSC2/CLKOUT	VDD - 0.7 VDD - 0.7	_ _	_ _	V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, PIC16C5X-RC		

<sup>\*</sup> These parameters are characterized but not tested.

- 2: Negative current is defined as coming out of the pin.
- **3:** For PIC16C5X-RC devices, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
- 4: The user may use the better of the two specifications.

<sup>†</sup> Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

**Note 1:** The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

FIGURE 12-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C54/55/56/57

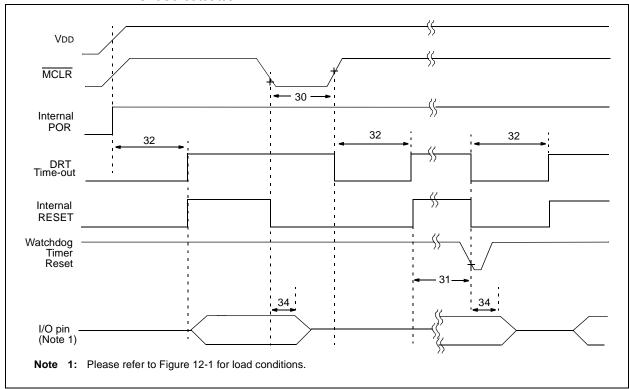


TABLE 12-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C54/55/56/57

AC Chara	cteristics	Standard Operating Conditions (u Operating Temperature $0^{\circ}C \le -40^{\circ}C \le -40^{\circ}C \le 10^{\circ}$	$TA \le +7$ $TA \le +8$	0°C for 5°C for	commei industria	rcial al	
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
30	TmcL	MCLR Pulse Width (low)	100*	_	_	ns	VDD = 5.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
32	TDRT	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)
34	Tioz	I/O Hi-impedance from MCLR Low — 100* ns					

<sup>\*</sup> These parameters are characterized but not tested.

<sup>†</sup> Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

#### 13.0 ELECTRICAL CHARACTERISTICS - PIC16CR54A

## Absolute Maximum Ratings(†)

Ambient Temperature under bias	55°C to +125°C
Storage Temperature	65°C to +150°C
Voltage on VDD with respect to Vss	0 to +7.5V
Voltage on MCLR with respect to Vss <sup>(1)</sup>	0 to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation <sup>(2)</sup>	800 mW
Max. current out of Vss pin	150 mA
Max. current into VDD pin	50 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, IIK (VI < 0 or VI > VDD)	±20 mA
Output clamp current, IOK (V0 < 0 or V0 > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O port (PORTA or B)	40 mA
Max. output current sunk by a single I/O port (PORTA or B)	50 mA

- **Note 1:** Voltage spikes below Vss at the  $\overline{MCLR}$  pin, inducing currents greater than 80 mA may cause latch-up. Thus, a series resistor of 50 to 100  $\Omega$  should be used when applying a low level to the  $\overline{MCLR}$  pin rather than pulling this pin directly to Vss.
  - 2: Power Dissipation is calculated as follows: PDIS = VDD x {IDD  $\sum$  IOH} +  $\sum$  {(VDD-VOH) x IOH} +  $\sum$ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

**AC Characteristics** 

TABLE 15-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A

**Standard Operating Conditions (unless otherwise specified)** 

Operating Temperature  $0^{\circ}C \le TA \le +70^{\circ}C$  for commercial  $-40^{\circ}C \le TA \le +85^{\circ}C$  for industrial

 $-20^{\circ}\text{C} \le \text{TA} \le +85^{\circ}\text{C}$  for industrial - PIC16LV54A-02I

 $-40^{\circ}C \le TA \le +125^{\circ}C$  for extended

Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
1	Tosc	External CLKIN Period <sup>(1)</sup>	250	_	_	ns	XT osc mode
			500	_	_	ns	XT osc mode (PIC16LV54A)
			250		_	ns	HS osc mode (04)
			100	_	_	ns	HS osc mode (10)
			50	_	_	ns	HS osc mode (20)
			5.0	_	1	μS	LP osc mode
		Oscillator Period <sup>(1)</sup>	250	_	_	ns	RC osc mode
			500	_	_	ns	RC osc mode (PIC16LV54A)
			250	_	10,000	ns	XT osc mode
			500	_	_	ns	XT osc mode (PIC16LV54A)
			250	_	250	ns	HS osc mode (04)
			100	_	250	ns	HS osc mode (10)
			50	_	250	ns	HS osc mode (20)
			5.0	_	200	μS	LP osc mode
2	Tcy	Instruction Cycle Time <sup>(2)</sup>	_	4/Fosc	_		
3	TosL, TosH	Clock in (OSC1) Low or	85*	_	1	ns	XT oscillator
		High Time	20*	_	_	ns	HS oscillator
			2.0*			μS	LP oscillator
4	TosR, TosF	Clock in (OSC1) Rise or	_	_	25*	ns	XT oscillator
		Fall Time	_	_	25*	ns	HS oscillator
			_	_	50*	ns	LP oscillator

<sup>\*</sup> These parameters are characterized but not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

  When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
  - 2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

<sup>†</sup> Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

## FIGURE 15-5: TIMER0 CLOCK TIMINGS - PIC16C54A

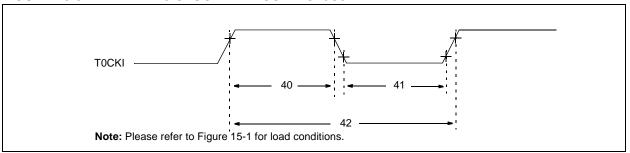


TABLE 15-4: TIMERO CLOCK REQUIREMENTS - PIC16C54A

TABLE 15-4:	HIMERO CLOC	K REQUIREMENTS	- PIC16C54A							
		Standard Operating	Standard Operating Conditions (unless otherwise specified)							
		Operating Temperatu	ure 0°C ≤	<b>T</b> A ≤ <b>+</b> 7	70°C fo	or comn	nercial			
AC Cha	racteristics		-40°C ≤	<b>T</b> A ≤ <b>+</b> 8	5°C fo	or indus	trial			
			<b>–</b> 20°C ≤	<b>T</b> A ≤ <b>+</b> 8	S5°C fo	or indus	trial - PIC16LV54A-02I			
			-40°C ≤	TA ≤ <b>+1</b>	25°C	for exte	nded			

Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High Pulse Width					
		- No Prescaler	0.5 Tcy + 20*	_	_	ns	
		- With Prescaler	10*	_	_	ns	
41	Tt0L	T0CKI Low Pulse Width					
		- No Prescaler	0.5 Tcy + 20*	_	_	ns	
		- With Prescaler	10*	_	_	ns	
42	Tt0P	T0CKI Period	20 or <u>Tcy + 40</u> * N	_	1		Whichever is greater.  N = Prescale Value (1, 2, 4,, 256)

<sup>\*</sup> These parameters are characterized but not tested.

<sup>†</sup> Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

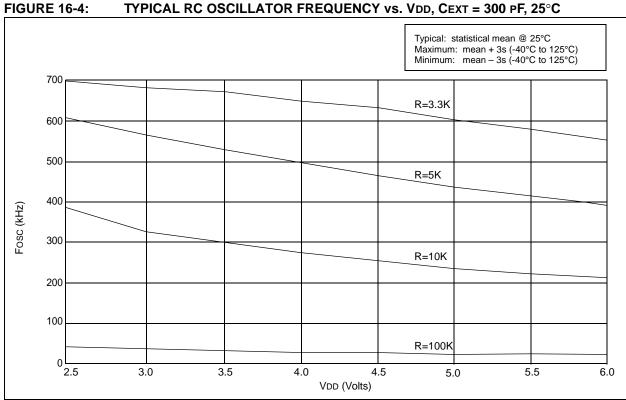


FIGURE 16-16: WDT TIMER TIME-OUT PERIOD vs. VDD<sup>(1)</sup>

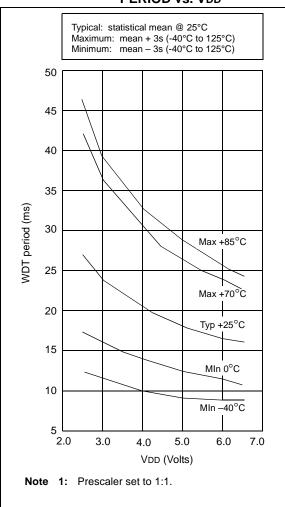
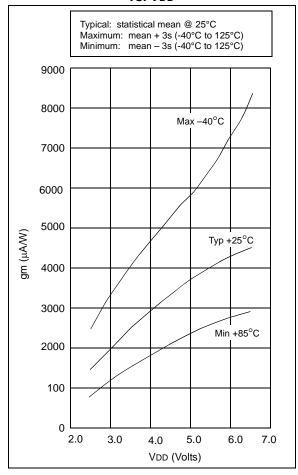
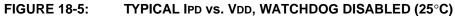


FIGURE 16-17: TRANSCONDUCTANCE (gm) OF HS OSCILLATOR vs. VDD



**FIGURE 18-4:** TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 300 PF, 25°C Typical: statistical mean @ 25°C Maximum: mean + 3s (-40°C to 125°C) Minimum: mean - 3s (-40°C to 125°C) 700 R=3.3K 600 500 R=5K Fosc (kHz) 400 300 R=10K 200 100 R=100K 0 2.5 3.0 3.5 5.0 6.0 VDD (Volts)



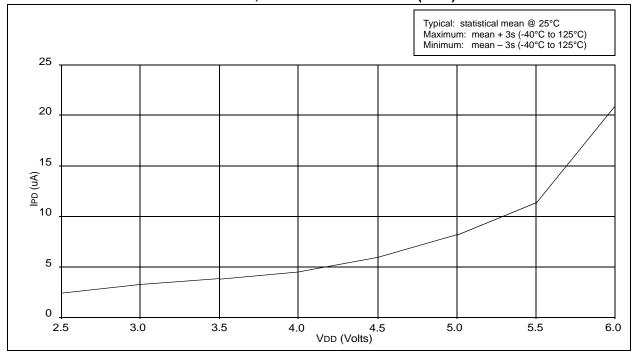


FIGURE 18-10: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF OSC1 INPUT (IN XT, HS AND LP MODES) vs. VDD

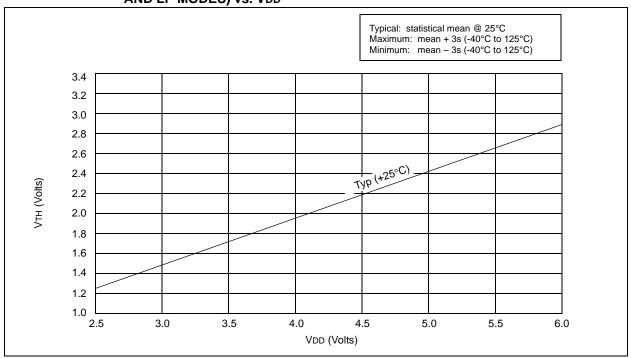
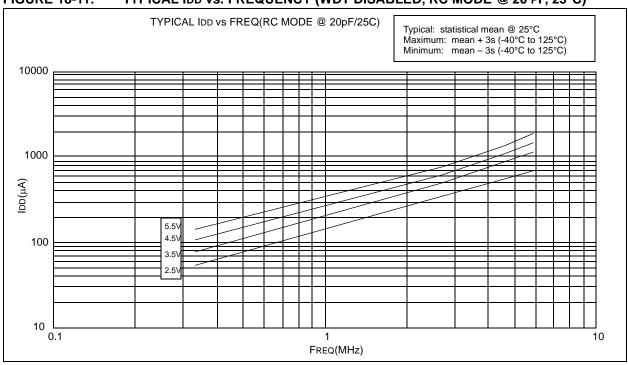


FIGURE 18-11: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 20 pF, 25°C)



#### 19.4 Timing Diagrams and Specifications

FIGURE 19-3: EXTERNAL CLOCK TIMING - PIC16C5X-40

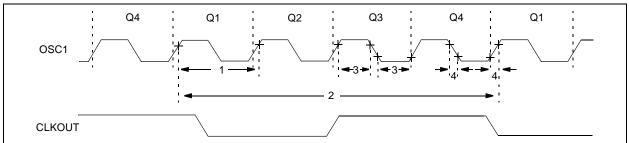


TABLE 19-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X-40

AC Characteristics		Standard Operating Conditions (unless otherwise specified)  Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial							
Param No.	Symbol	Characteristic		Typ†	Max	Units	Conditions		
	Fosc	External CLKIN Frequency <sup>(1)</sup>	20	_	40	MHz	HS osc mode		
1	Tosc	External CLKIN Period <sup>(1)</sup>	25	_	_	ns	HS osc mode		
2	Tcy	Instruction Cycle Time <sup>(2)</sup>	_	4/Fosc	_	_			
3	TosL, TosH	Clock in (OSC1) Low or High Time	6.0*	_	_	ns	HS oscillator		
4	TosR, TosF	Clock in (OSC1) Rise or Fall Time	_	_	6.5*	ns	HS oscillator		

<sup>\*</sup> These parameters are characterized but not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

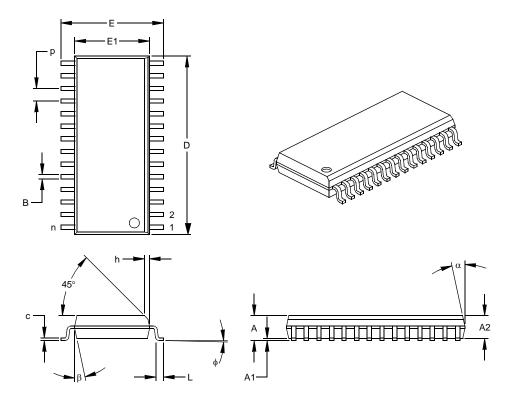
  When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
  - 2: Instruction cycle period (TcY) equals four times the input oscillator time base period.

<sup>†</sup> Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

## 28-Lead Plastic Small Outline (SO) - Wide, 300 mil (SOIC)

Note:

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



		INCHES*		MILLIMETERS			
Dimension	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		28			28	
Pitch	р		.050			1.27	
Overall Height	Α	.093	.099	.104	2.36	2.50	2.64
Molded Package Thickness	A2	.088	.091	.094	2.24	2.31	2.39
Standoff §	A1	.004	.008	.012	0.10	0.20	0.30
Overall Width	Е	.394	.407	.420	10.01	10.34	10.67
Molded Package Width	E1	.288	.295	.299	7.32	7.49	7.59
Overall Length	D	.695	.704	.712	17.65	17.87	18.08
Chamfer Distance	h	.010	.020	.029	0.25	0.50	0.74
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle Top	ф	0	4	8	0	4	8
Lead Thickness	С	.009	.011	.013	0.23	0.28	0.33
Lead Width	В	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top		0	12	15	0	12	15
Mold Draft Angle Bottom		0	12	15	0	12	15

Notes:

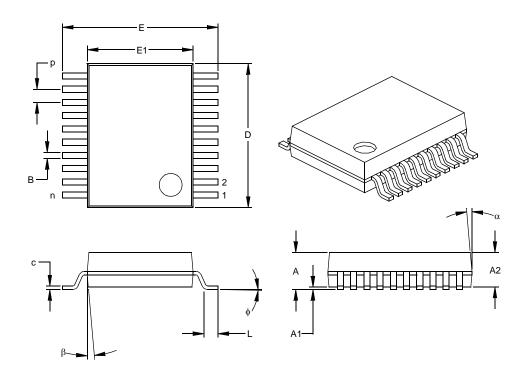
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-013 Drawing No. C04-052

<sup>\*</sup> Controlling Parameter § Significant Characteristic

## 20-Lead Plastic Shrink Small Outline (SS) - 209 mil, 5.30 mm (SSOP)

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



		INCHES*			MILLIMETERS			
Dimension	MIN	NOM	MAX	MIN	NOM	MAX		
Number of Pins	n		20			20		
Pitch	р		.026			0.65		
Overall Height	Α	.068	.073	.078	1.73	1.85	1.98	
Molded Package Thickness	A2	.064	.068	.072	1.63	1.73	1.83	
Standoff §	A1	.002	.006	.010	0.05	0.15	0.25	
Overall Width	Е	.299	.309	.322	7.59	7.85	8.18	
Molded Package Width	E1	.201	.207	.212	5.11	5.25	5.38	
Overall Length	D	.278	.284	.289	7.06	7.20	7.34	
Foot Length	L	.022	.030	.037	0.56	0.75	0.94	
Lead Thickness	С	.004	.007	.010	0.10	0.18	0.25	
Foot Angle	ф	0	4	8	0.00	101.60	203.20	
Lead Width	В	.010	.013	.015	0.25	0.32	0.38	
Mold Draft Angle Top	α	0	5	10	0	5	10	
Mold Draft Angle Bottom	β	0	5	10	0	5	10	

<sup>\*</sup> Controlling Parameter

#### Notes

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.
JEDEC Equivalent: MO-150
Drawing No. C04-072

<sup>§</sup> Significant Characteristic